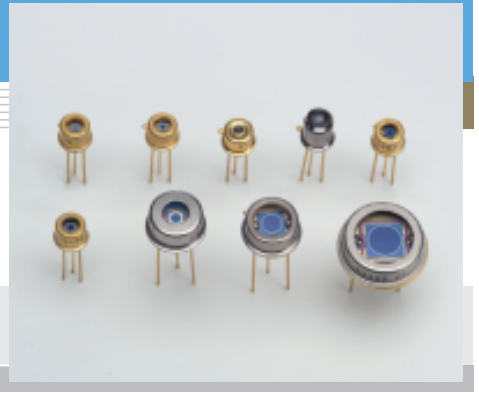


Si APD

S2381 to S2385, S5139, S8611, S3884

Low bias operation, for 800 nm band



Features

- Stable operation at low bias
- High-speed response
- High sensitivity and low noise

Applications

- Spatial light transmission
- Rangefinder

■ General ratings / Absolute maximum ratings

Type No.	Dimensional outline/ Window material * ¹	Package	Active area * ² size (mm)	Effective active area (mm ²)	Absolute maximum ratings		
					Operating temperature T _{opr} (°C)	Storage temperature T _{stg} (°C)	
S2381	①/K	TO-18	φ0.2	0.03	-20 to +85	-55 to +125	
S2382			φ0.5	0.19			
S5139							
S8611			φ1.0	0.78			
S2383	①/K	TO-5					
S2383-10 * ³		φ1.5	1.77				
S3884	④/K		TO-5				
S2384	⑤/K	φ3.0	7.0				
S2385	⑥/K	TO-8	φ5.0	19.6			

■ Electrical and optical characteristics (Typ. T_a=25 °C, unless otherwise noted)

Type No.	Spectral response range λ (nm)	Peak *4 sensitivity wavelength λ_p (nm)	Photo sensitivity S M=1 $\lambda=800\text{ nm}$ (A/W)	Quantum efficiency QE M=1 $\lambda=800\text{ nm}$ (%)	Breakdown voltage VBR ID=100 μ A		Temp. coefficient of VBR (V/°C)	Dark current *4 ID		Cut-off *4 frequency fc RL=50 Ω (MHz)	Terminal *4 capacitance Ct (pF)	Excess Noise figure *4 x $\lambda=800\text{ nm}$	Gain M $\lambda=800\text{ nm}$
					Typ. (V)	Max. (V)		Typ. (nA)	Max. (nA)				
S2381	400 to 1000	800	0.5	75	150	200	0.65	0.05	0.5	1000	1.5	0.3	100
S2382													
S5139								0.1	1	900	3		
S8611													
S2383								0.2	2	600	6		
S2383-10 *3													
S3884								0.5	5	400	10		
S2384								1	10	120	40		
S2385								3	30	40	95		
												40	

*1: Window material K: borosilicate glass, L: lens type borosilicate glass

*2: Active area in which a typical gain can be obtained

*3: This is a variant of S2383 in which the device chip is light-shielded by aluminum coating except for the active area

*4: Measured under conditions that the device is operated at the gain listed in the specification table

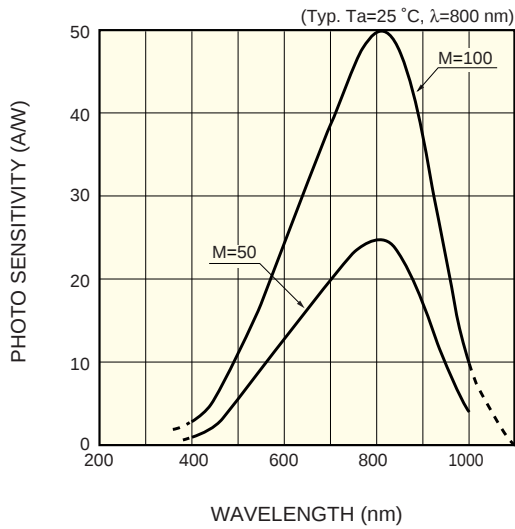
Note) The following different breakdown voltage ranges are available.

S2381, S2382, S5139, S8611, S3884: -01 (80 to 120 V), -02 (120 to 160 V), -03 (160 to 200 V)

S2381-10: -10A (80 to 120 V), -10B (120 to 160 V), -10C (160 to 200 V)

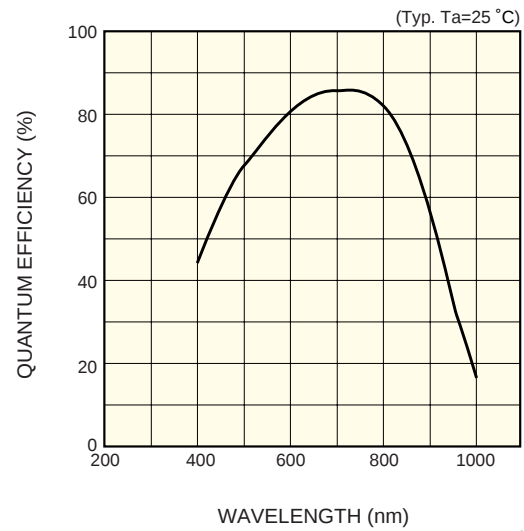
SOLID STATE DIVISION

Spectral response



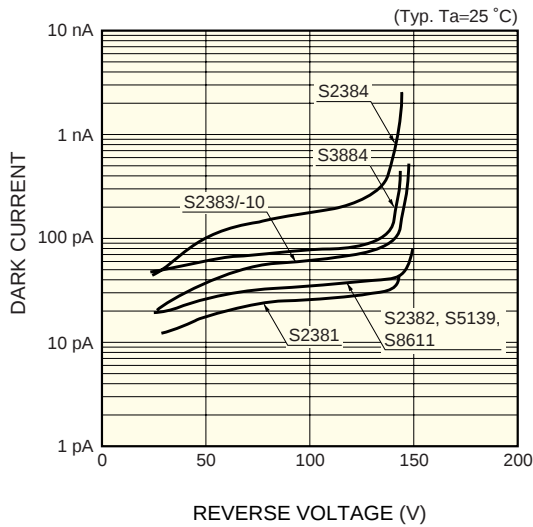
KAPDB0020EB

Quantum efficiency vs. wavelength



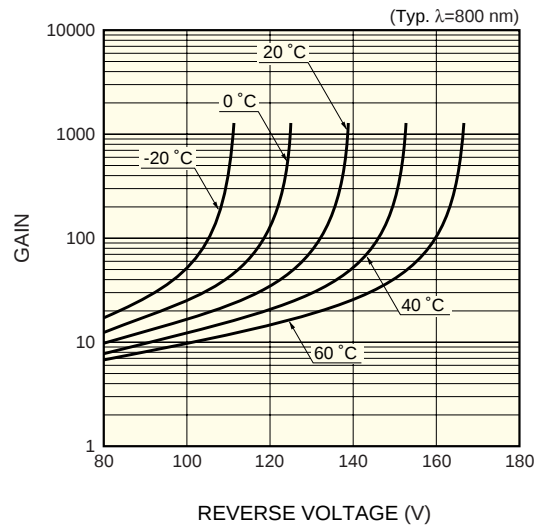
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Dark current vs. reverse voltage



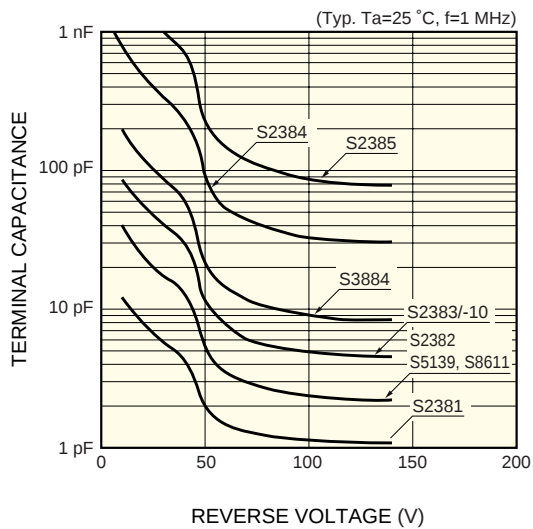
KAPDB0016EC

Gain vs. reverse voltage



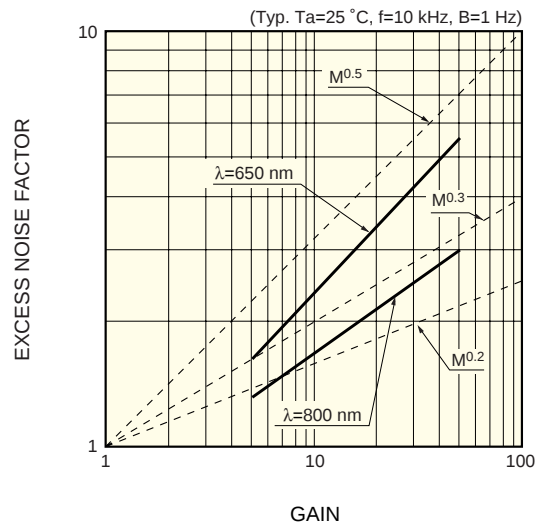
KAPDB0017EC

Terminal capacitance vs. reverse voltage



KAPDB0018EC

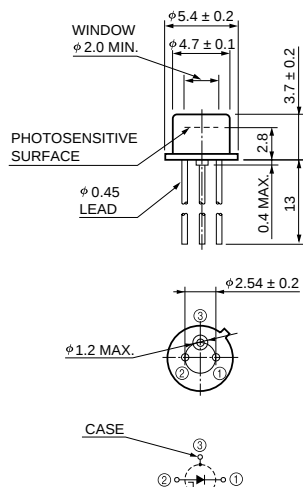
Excess noise factor vs. gain



KAPDB0022EA

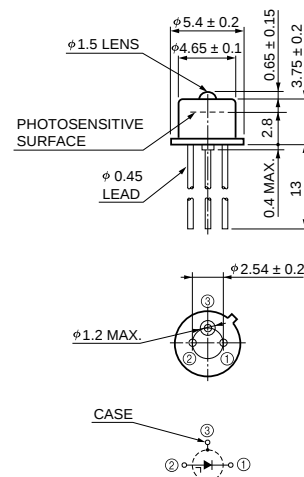
Dimensional outlines (unit: mm)

① S2381, S2382, S2383/-10



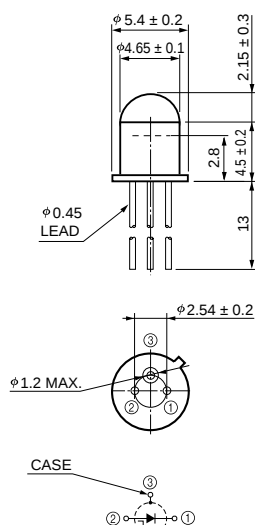
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② S5139



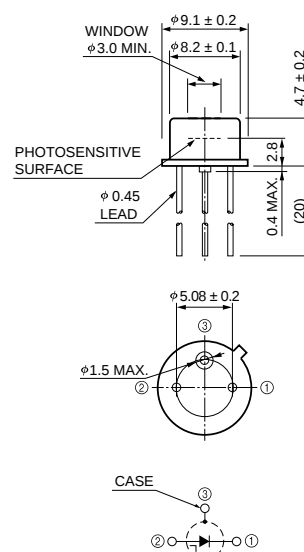
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③ S8611



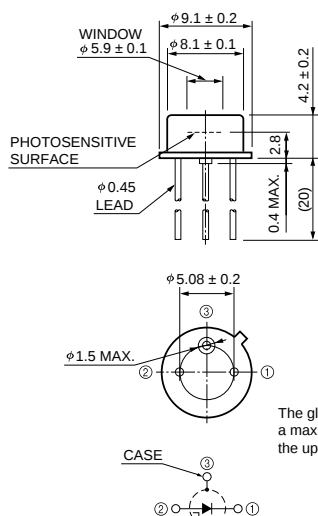
KAPDA0031EA

④ S3884



KAPDA0011EB

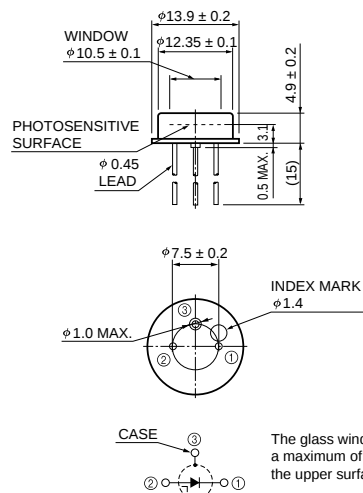
⑤ S2384



The glass window may extend a maximum of 0.2 mm beyond the upper surface of the cap.

KAPDA0012EA

⑥ S2385



The glass window may extend a maximum of 0.2 mm beyond the upper surface of the cap.

KAPDA0013ED

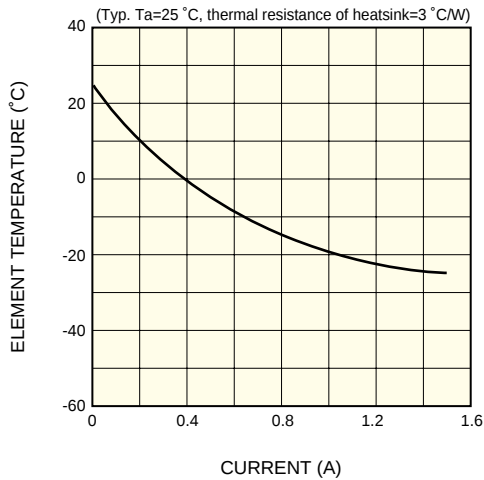
TE-cooled type APD S4315 series

Parameter	Symbol	Condition	S4315	S4315-01	S4315-02	Unit
APD	-		S2381	S2382	S2383	-
Effective active area *5	-		$\phi 0.2$	$\phi 0.5$	$\phi 1.0$	mm
Spectral response range	λ		400 to 1000			nm
Peak sensitivity wavelength	λ_p	M=100	800			nm
Cooling temperature	ΔT		35			°C
Package	-		TO-8			-

*5: Active area in which a typical gain can be obtained.

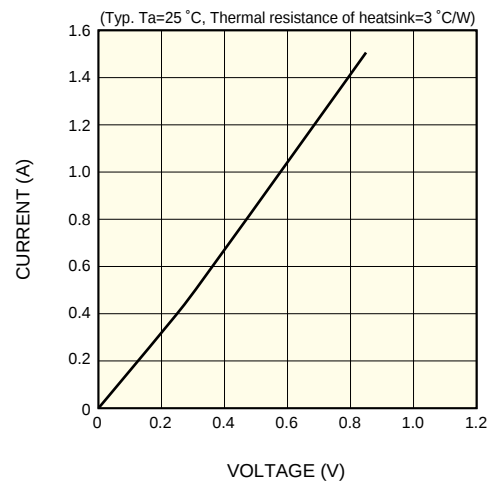
We welcome your request for active areas different from those listed above.

Cooling characteristic of TE-cooler



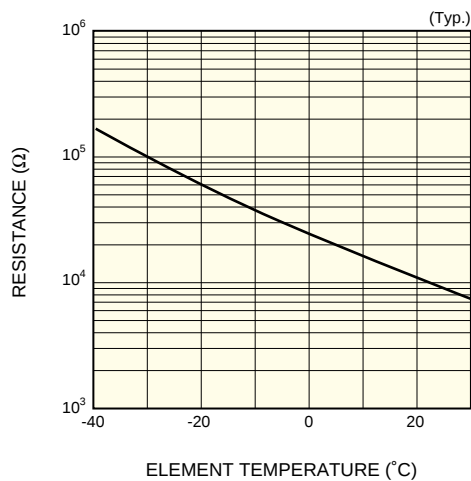
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Current vs. voltage characteristic of TE-cooler



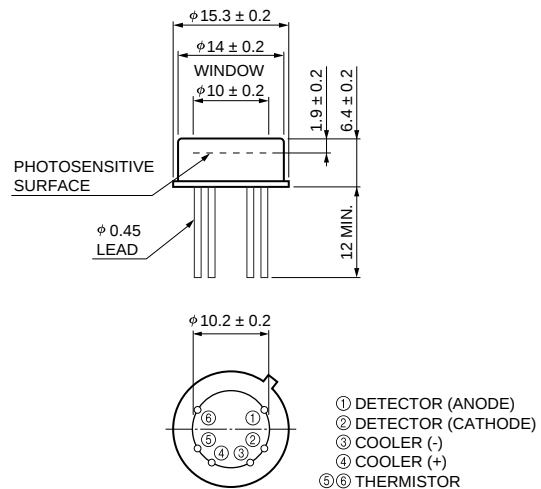
KAPDB0100EA

Thermistor temperature characteristic



KIRD80116EA

Dimensional outline (unit: mm)



KAPDA0020EA